Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass and metal

Overall Length:

0.673 inches

Overall Diameter:

Between 0.501 inches and 0.505 inches

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 breakover voltage, dc

Current Rating Per Characteristic:

10.00 amperes source cutoff current preset

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius case

Special Features:

Junction pattern arrangement: pnpn

Test Data Document:

07397-13-811553 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead w/terminal lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0